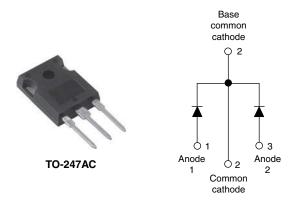
Vishay Semiconductors

www.vishay.com

Ultrafast Rectifier, 2 x 40 A FRED Pt[®]



PRODUCT SUMMARY				
Package	TO-247AC			
I _{F(AV)}	2 x 40 A			
V _R	200 V			
V _F at I _F	1.02 V			
t _{rr} typ.	34 ns			
T _J max.	175 °C			
Diode variation	Common cathode			

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to HALOGEN JEDEC-JESD47
 HALOGEN
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTIONS/APPLICATIONS

VS-80CPU02... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of welding, SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Repetitive peak reverse voltage	V _{RRM}		200	V
per leg		T _C = 145 °C	40	
Average rectified forward current total	device I _{F(AV)}		80	А
Non-repetitive peak surge current per leg	g I _{FSM}	T _J = 25 °C	330	
Operating junction and storage temperat	tures T _J , T _{Stg}		- 65 to 175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-		
		I _F = 40 A	-	0.94	1.02		
Forward voltage	V _F	I _F = 40 A, T _J = 150 °C	-	0.80	0.90	V	
		I _F = 80 A	-	1.07	1.20		
		I _F = 80 A, T _J = 150 °C	-	0.97	1.08		
	I _R	$V_{R} = V_{R}$ rated	-	-	5		
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$		500	μΑ		
Junction capacitance	CT	V _R = 200 V	-	120	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body - 3.5 - r		nH			

Revision: 30-Sep-11

1



RoHS

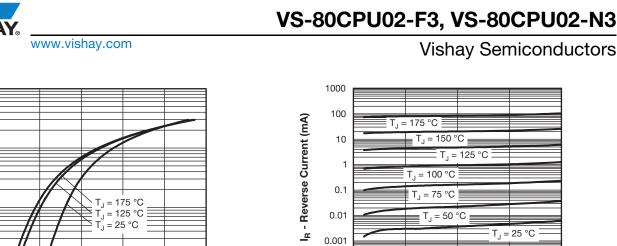
COMPLIANT



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	34	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	33	-	ns
	T _J = 125 °C		-	54	-		
Peak recovery current I _{RRM}		T _J = 25 °C	$I_F = 40 \text{ A}$	-	3.4	-	А
	T _J = 125 °C	dl _F /dt = - 200 A/µs V _B = 200 V	-	8	-	~	
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	56	-	nC
	T _J = 125 °C]	-	216	-		

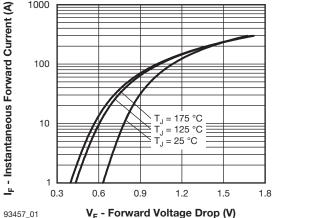
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}		-	0.46	0.70	
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount		-	40	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.3	-	
Weight			-	6.0	-	g
Weight			-	0.21	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC	80CPU02			



0.0001

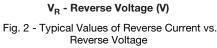
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0



1000

Fig. 1 - Typical Forward Voltage Drop Characteristics



100

50



150

200

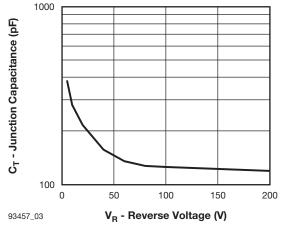


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

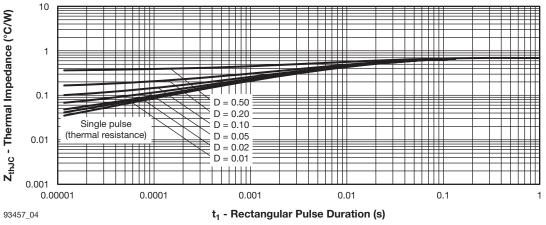
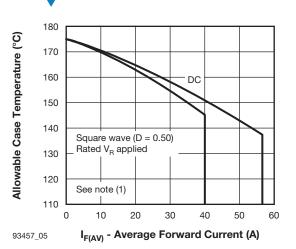


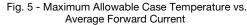
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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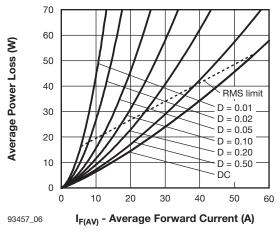
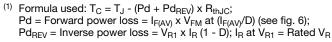
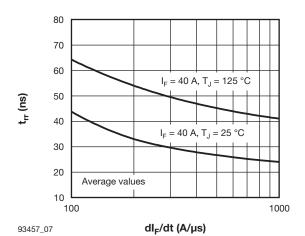


Fig. 6 - Forward Power Loss Characteristics

Note







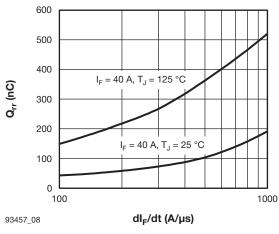


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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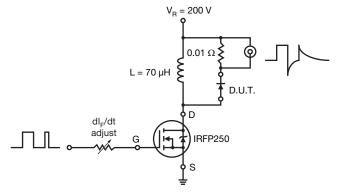
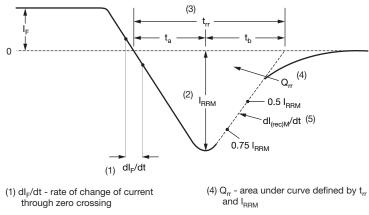


Fig. 9 - Reverse Recovery Parameter Test Circuit

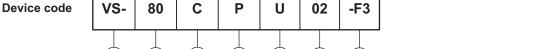


$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 $I_{\rm RRM}$ and 0.50 $I_{\rm RRM}$ extrapolated to zero current. Fig. 9 - Reverse Recovery Waveform and Definitions

(2) I_{RRM} - peak reverse recovery current

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}



(6)

7

(5)

1 - Vishay Semiconductors product

(4)

2 - Current rating (80 = 80 A)

(3)

- Circuit configuration:

C = Common cathode

- P = TO-247AC

1

3

4

5 6

7

(2)

- U = Ultrafast rectifier
- Voltage rating (02 = 200 V)
- Environmental digit:

-F3 = RoHS compliant and totally lead (Pb)-free

-N3 = Halogen-free, RoHS compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-80CPU02-F3	25	500	Antistatic plastic tube			
VS-80CPU02-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95223			
Part marking	www.vishay.com/doc?95007			

VS-80CPU02-F3, VS-80CPU02-N3

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ORDERING INFORMATION TABLE



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